2SD2528

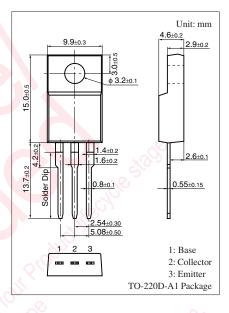
Silicon NPN epitaxial planar type

For power amplification and high-current amplification

Features

- \bullet High forward current transfer ratio h_{FE}
- \bullet Satisfactory linearity of forward current transfer ratio $h_{\rm FE}$
- Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings $T_a = 25^{\circ}C$ Parameter Symbol Rating Unit Collector-base voltage (Emitter open) V_{CBO} 80 V Collector-emitter voltage (Base open) V_{CEO} 60 V Emitter-base voltage (Collector open) V V_{EBO} 6 5 Collector current IC A Peak collector current I_{CP} 10 Α Base current I_B 1 А $T_C = 25^{\circ}C$ Collector power P_{C} 40 W dissipation 2.0 150 °C Junction temperature Ti Storage temperature T_{stg} -55 to +150 °C



Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

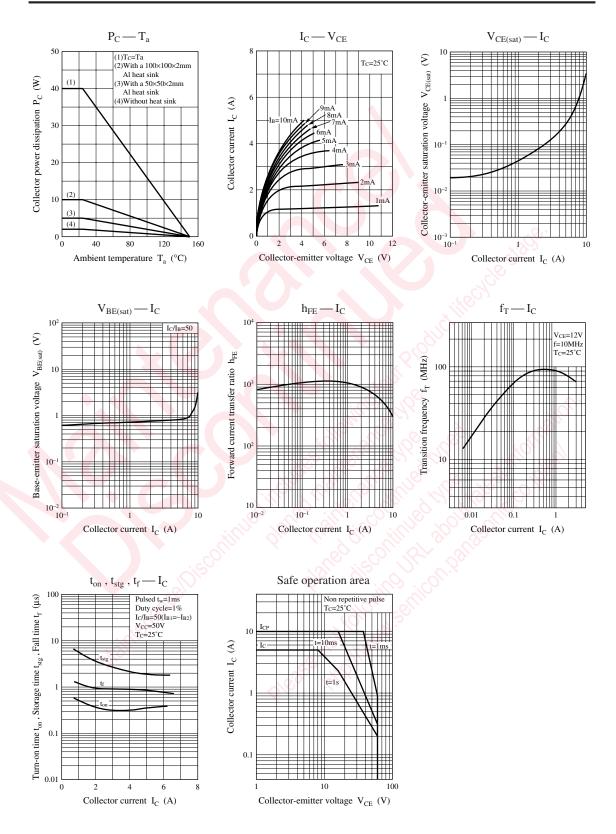
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 25 \text{ mA}, I_{\rm B} = 0$	60	0-		V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 80 \text{ V}, I_E = 0$	$\sim 2^{\circ}$		100	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 6 V, I_C = 0$			100	μΑ
Forward current transfer ratio	h _{FE} *	$V_{CE} = 4 V, I_C = 1 A$	500		2000	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 4 \text{ A}, I_{\rm B} = 0.1 \text{ A}$			0.3	V
Transition frequency	f _T	$V_{CE} = 12 \text{ V}, I_C = 0.4 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_{C} = 4 A, I_{B1} = 0.08 A, I_{B2} = -0.08 A$		0.4		μs
Storage time	t _{stg}	$V_{\rm CC} = 50 \text{ V}$		2.0		μs
Fall time	t _f	Q100 1.		0.6		μs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Q	Р		
h _{FE1}	500 to 1 200	800 to 2000		

Panasonic



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